

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Patent Application of:  
Euijoon Yoon *et al.*

Application No.: 10/563,854

Confirmation No.: 3828

Filed: June 9, 2006

Art Unit: 2823

For: GROWTH METHOD FOR NITRIDE  
SEMICONDUCTOR EPITAXIAL LAYERS

Examiner: Maldonado, Julio J.

**AMENDMENT IN RESPONSE TO NON-FINAL OFFICE ACTION**

MS Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

August 4, 2009

Dear Sir:

**INTRODUCTORY COMMENTS**

In response to the Non-Final Office Action dated March 4, 2009, please amend the above-identified U.S. patent application as follows.

**Amendments to the Claims** are reflected in the listing of claims which begins on page 2 of this paper.

**Remarks/Arguments** begin on page 8 of this paper.